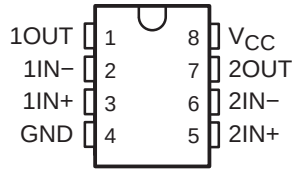
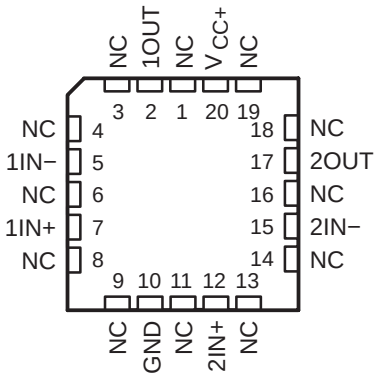
- **Wide Supply Range:**
  - **Single Supply . . . 3 V to 32 V (26 V for LM2904)**
  - **or Dual Supplies . . . ±1.5 V to ±16 V (±13 V for LM2904)**
- **Low Supply-Current Drain, Independent of Supply Voltage . . . 0.7 mA Typ**
- **Common-Mode Input Voltage Range Includes Ground, Allowing Direct Sensing Near Ground**
- **Low Input Bias and Offset Parameters:**
  - **Input Offset Voltage . . . 3 mV Typ**
    A Versions . . . 2 mV Typ
  - **Input Offset Current . . . 2 nA Typ**
  - **Input Bias Current . . . 20 nA Typ**
    A Versions . . . 15 nA Typ
- **Differential Input Voltage Range Equal to Maximum-Rated Supply Voltage . . . 32 V (26 V for LM2904)**
- **Open-Loop Differential Voltage Amplification . . . 100 V/mV Typ**
- **Internal Frequency Compensation**

LM158, LM158A . . . JG PACKAGE
LM258, LM258A . . . D, DGK, OR P PACKAGE
LM358 . . . D, DGK, P, PS, OR PW PACKAGE
LM358A . . . D, DGK, P, OR PW PACKAGE
LM2904 . . . D, DGK, P, PS, OR PW PACKAGE
(TOP VIEW)



LM158, LM158A . . . FK PACKAGE
(TOP VIEW)



NC − No internal connection

description/ordering information

These devices consist of two independent, high-gain, frequency-compensated operational amplifiers designed to operate from a single supply over a wide range of voltages. Operation from split supplies also is possible if the difference between the two supplies is 3 V to 32 V (3 V to 26 V for the LM2904), and V_{CC} is at least 1.5 V more positive than the input common-mode voltage. The low supply-current drain is independent of the magnitude of the supply voltage.

Applications include transducer amplifiers, dc amplification blocks, and all the conventional operational amplifier circuits that now can be implemented more easily in single-supply-voltage systems. For example, these devices can be operated directly from the standard 5-V supply used in digital systems and easily can provide the required interface electronics without additional ±5-V supplies.

description/ordering information (continued)

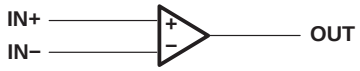
ORDERING INFORMATION

T_A	V_{IO}max AT 25°C	MAX TESTED V_{CC}	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	7 mV	30 V	PDIP (P)	Tube of 50	LM358P	LM358P
			SOIC (D)	Tube of 75	LM358D	LM358
				Reel of 2500	LM358DR	
			SOP (PS)	Reel of 2000	LM358PSR	L358
			TSSOP (PW)	Tube of 150	LM358PW	L358
				Reel of 2000	LM358PWR	
			MSOP/VSSOP (DGK)	Reel of 2500	LM358DGKR	M5_‡
	3 mV	30 V	PDIP (P)	Tube of 50	LM358AP	LM358AP
			SOIC (D)	Tube of 75	LM358AD	LM358A
				Reel of 2500	LM358ADR	
			TSSOP (PW)	Tube of 150	LM358APW	L358A
				Reel of 2000	LM358APWR	
			MSOP/VSSOP (DGK)	Reel of 2500	LM358ADGKR	M6_‡
−25°C to 85°C	5 mV	30 V	PDIP (P)	Tube of 50	LM258P	LM258P
			SOIC (D)	Tube of 75	LM258D	LM258
				Reel of 2500	LM258DR	
			MSOP/VSSOP (DGK)	Reel of 2500	LM258DGKR	M2_‡
	3 mV	30 V	PDIP (P)	Tube of 50	LM258AP	LM258AP
			SOIC (D)	Tube of 75	LM258AD	LM258A
				Reel of 2500	LM258ADR	
			MSOP/VSSOP (DGK)	Reel of 2500	LM258ADGKR	M3_‡
−40°C to 125°C	7 mV	26 V	PDIP (P)	Tube of 50	LM2904P	LM2904P
			SOIC (D)	Tube of 75	LM2904D	LM2904
				Reel of 2500	LM2904DR	
			SOP (PS)	Reel of 2000	LM2904PSR	L2904
			TSSOP (PW)	Tube of 150	LM2904PW	L2904
				Reel of 2000	LM2904PWR	
			MSOP/VSSOP (DGK)	Reel of 2500	LM2904DGKR	MB_‡
	7 mV	32 V	SOIC (D)	Reel of 2500	LM2904VQDR	L2904V
			TSSOP (PW)	Reel of 2000	LM2904VQPWR	L2904V
	2 mV	32 V	SOIC (D)	Reel of 2500	LM2904AVQDR	L2904AV
			TSSOP (PW)	Reel of 2000	LM2904AVQPWR	L2904AV
−55°C to 125°C	5 mV	30 V	CDIP (JG)	Tube of 50	LM158JG	LM158JG
			LCCC (FK)	Tube of 55	LM158FK	LM158FK
	2 mV	30 V	CDIP (JG)	Tube of 50	LM158AJG	LM158AJG
			LCCC (FK)	Tube of 55	LM158AFK	LM158AFK

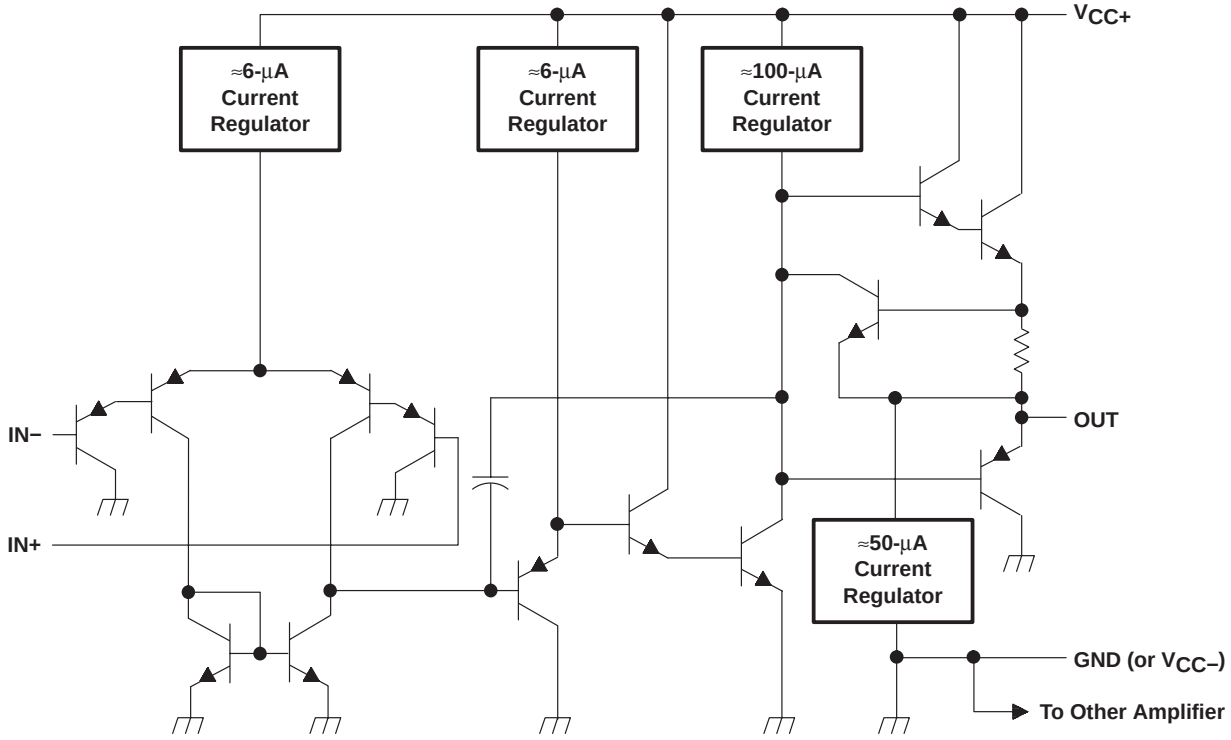
† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

‡ The actual top-side marking has one additional character that designates the assembly/test site.

symbol (each amplifier)



schematic (each amplifier)



COMPONENT COUNT	
Epi-FET	1
Diodes	2
Resistors	7
Transistors	51
Capacitors	2

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

		LM158, LM158A LM258, LM258A LM358, LM358A LM2904V	LM2904	UNIT
Supply voltage, V_{CC} (see Note 1)		±16 or 32	±13 or 26	V
Differential input voltage, V_{ID} (see Note 2)		±32	±26	V
Input voltage, V_I (either input)		−0.3 to 32	−0.3 to 26	V
Duration of output short circuit (one amplifier) to ground at (or below) 25°C free-air temperature (V_{CC} ≤ 15 V) (see Note 3)		Unlimited	Unlimited	
Package thermal impedance, θ_{JA} (see Notes 4 and 5)	D package	97	97	°C/W
	DGK package	172	172	
	P package	85	85	
	PS package	95	95	
	PW package	149	149	
Package thermal impedance, θ_{JC} (see Notes 6 and 7)	FK package	5.61		°C/W
	JG package	14.5		
Operating free-air temperature range, T_A	LM158, LM158A	−55 to 125		°C
	LM258, LM258A	−25 to 85		
	LM358, LM358A	0 to 70		
	LM2904	−40 to 125	−40 to 125	
Operating virtual junction temperature, T_J		150	150	°C
Case temperature for 60 seconds	FK package	260		°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300	300	°C
Storage temperature range, T_{stg}		−65 to 150	−65 to 150	°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES:
1. All voltage values, except differential voltages and V_{CC} specified for measurement of I_{OS}, are with respect to the network ground terminal.
2. Differential voltages are at IN+ with respect to IN−.
3. Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.
4. Maximum power dissipation is a function of $T_J(max)$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
5. The package thermal impedance is calculated in accordance with JESD 51-7.
6. Maximum power dissipation is a function of $T_J(max)$, θ_{JC}, and T_C. The maximum allowable power dissipation at any allowable case temperature is $P_D = (T_J(max) - T_C)/\theta_{JC}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
7. The package thermal impedance is calculated in accordance with MIL-STD-883.

electrical characteristics at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		T_A‡	LM158 LM258			LM358			UNIT
					MIN	TYP§	MAX	MIN	TYP§	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5 V to MAX, $V_{IC} = V_{ICR(min)}$, V_O = 1.4 V		25°C		3	5		3	7	mV
				Full range			7			9	
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage			Full range		7			7		μV/°C
I_{IO}	Input offset current	V_O = 1.4 V		25°C		2	30		2	50	nA
				Full range			100			150	
$\alpha_{I_{IO}}$	Average temperature coefficient of input offset current			Full range		10			10		pA/°C
I_{IB}	Input bias current	V_O = 1.4 V		25°C		−20	−150		−20	−250	nA
				Full range			−300			−500	
V_{ICR}	Common-mode input voltage range	V_{CC} = 5 V to MAX		25°C	0 to V_{CC} − 1.5			0 to V_{CC} − 1.5			V
				Full range	0 to V_{CC} − 2			0 to V_{CC} − 2			
V_{OH}	High-level output voltage	$R_L \geq 2$ kΩ		25°C	V_{CC} − 1.5			V_{CC} − 1.5			V
		$R_L \geq 10$ kΩ		25°C							
		V_{CC} = MAX	R_L = 2 kΩ	Full range	26			26			
			$R_L \geq 10$ kΩ	Full range	27	28		27	28		
V_{OL}	Low-level output voltage	$R_L \leq 10$ kΩ		Full range		5	20		5	20	mV
A_{VD}	Large-signal differential voltage amplification	V_{CC} = 15 V, V_O = 1 V to 11 V, $R_L \geq 2$ kΩ		25°C	50	100		25	100		V/mV
				Full range	25			15			
CMRR	Common-mode rejection ratio	V_{CC} = 5 V to MAX, $V_{IC} = V_{ICR(min)}$		25°C	70	80		65	80		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{CC} = 5 V to MAX		25°C	65	100		65	100		dB
V_{O1}/V_{O2}	Crosstalk attenuation	f = 1 kHz to 20 kHz		25°C		120			120		dB
I_O	Output current	V_{CC} = 15 V, V_{ID} = 1 V, V_O = 0	Source	25°C	−20	−30		−20	−30		mA
				Full range	−10			−10			
		V_{CC} = 15 V, V_{ID} = −1 V, V_O = 15 V	Sink	25°C	10	20		10	20		
				Full range	5			5			
I_O	Output current	V_{ID} = −1 V, V_O = 200 mV		25°C	12	30		12	30		μA
I_{OS}	Short-circuit output current	V_{CC} at 5 V, GND at −5 V, V_O = 0		25°C		±40	±60		±40	±60	mA
I_{CC}	Supply current (two amplifiers)	V_O = 2.5 V, No load		Full range		0.7	1.2		0.7	1.2	mA
		V_{CC} = MAX, V_O = 0.5 V, No load		Full range		1	2		1	2	

† All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 26 V for the LM2904 and 30 V for others.
‡ Full range is −55°C to 125°C for LM158, −25°C to 85°C for LM258, 0°C to 70°C for LM358, and −40°C to 125°C for LM2904.
§ All typical values are at T_A = 25°C.

electrical characteristics at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		T_A‡	LM2904			UNIT
					MIN	TYP§	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5 V to MAX, $V_{IC} = V_{ICR(min)}$, V_O = 1.4 V	Non-A devices	25°C		3	7	mV
				Full range			10	
			A-suffix devices	25°C		1	2	
				Full range			4	
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage			Full range		7		µV/°C
I_{IO}	Input offset current	V_O = 1.4 V	Non-V device	25°C		2	50	nA
				Full range			300	
			V-suffix device	25°C		2	50	
				Full range			150	
$\alpha_{I_{IO}}$	Average temperature coefficient of input offset current			Full range		10		pA/°C
I_{IB}	Input bias current	V_O = 1.4 V		25°C		−20	−250	nA
				Full range			−500	
V_{ICR}	Common-mode input voltage range	V_{CC} = 5 V to MAX		25°C	0 to V_{CC} − 1.5			V
				Full range	0 to V_{CC} − 2			
V_{OH}	High-level output voltage	$R_L \geq 10\ k\Omega$		25°C	V_{CC} − 1.5			V
		V_{CC} = MAX, Non-V device	R_L = 2 kΩ	Full range	22			
			$R_L \geq 10\ k\Omega$	Full range	23	24		
		V_{CC} = MAX, V-suffix device	R_L = 2 kΩ	Full range	26			
			$R_L \geq 10\ k\Omega$	Full range	27	28		
V_{OL}	Low-level output voltage	$R_L \leq 10\ k\Omega$		Full range		5	20	mV
A_{VD}	Large-signal differential voltage amplification	V_{CC} = 15 V, V_O = 1 V to 11 V, $R_L \geq 2\ k\Omega$		25°C	25	100		V/mV
				Full range	15			
CMRR	Common-mode rejection ratio	V_{CC} = 5 V to MAX, $V_{IC} = V_{ICR(min)}$	Non-V device	25°C	50	80		dB
			V-suffix device	25°C	65	80		
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{CC} = 5 V to MAX		25°C	65	100		dB
V_{O1}/V_{O2}	Crosstalk attenuation	f = 1 kHz to 20 kHz		25°C		120		dB
I_O	Output current	V_{CC} = 15 V, V_{ID} = 1 V, V_O = 0	Source	25°C	−20	−30		mA
				Full range	−10			mA
		V_{CC} = 15 V, V_{ID} = −1 V, V_O = 15 V	Sink	25°C	10	20		mA
				Full range	5			mA
		V_{ID} = −1 V, V_O = 200 mV	Non-V device	25°C		30		µA
			V-suffix device	25°C	12	40		
I_{OS}	Short-circuit output current	V_{CC} at 5 V, GND at −5 V, V_O = 0		25°C		±40	±60	mA
I_{CC}	Supply current (two amplifiers)	V_O = 2.5 V, No load		Full range		0.7	1.2	mA
		V_{CC} = MAX, V_O = 0.5 V, No load		Full range		1	2	

† All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 26 V for the LM2904, 32 V for the LM2904V, and 30 V for others.
‡ Full range is −55°C to 125°C for LM158, −25°C to 85°C for LM258, 0°C to 70°C for LM358, and −40°C to 125°C for LM2904.
§ All typical values are at T_A = 25°C.

electrical characteristics at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		T_A‡	LM158A			LM258A			UNIT
					MIN	TYP§	MAX	MIN	TYP§	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5 V to 30 V, $V_{IC} = V_{ICR(min)}$, V_O = 1.4 V		25°C			2		2	3	mV
				Full range			4			4	
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage			Full range		7	15*		7	15	µV/°C
I_{IO}	Input offset current	V_O = 1.4 V		25°C		2	10		2	15	nA
				Full range			30			30	
$\alpha_{I_{IO}}$	Average temperature coefficient of input offset current			Full range		10	200		10	200	pA/°C
I_{IB}	Input bias current	V_O = 1.4 V		25°C		−15	−50		−15	−80	nA
				Full range			−100			−100	
V_{ICR}	Common-mode input voltage range	V_{CC} = 30 V		25°C	0 to V_{CC} − 1.5			0 to V_{CC} − 1.5			V
				Full range	0 to V_{CC} − 2			0 to V_{CC} − 2			
V_{OH}	High-level output voltage	$R_L \geq 2$ kΩ		25°C	V_{CC} − 1.5			V_{CC} − 1.5			V
		V_{CC} = 30 V	R_L = 2 kΩ	Full range	26			26			
			$R_L \geq 10$ kΩ	Full range	27	28		27	28		
V_{OL}	Low-level output voltage	$R_L \leq 10$ kΩ		Full range		5	20		5	20	mV
A_{VD}	Large-signal differential voltage amplification	V_{CC} = 15 V, V_O = 1 V to 11 V, $R_L \geq 2$ kΩ		25°C	50	100		50	100		V/mV
				Full range	25			25			
CMRR	Common-mode rejection ratio			25°C	70	80		70	80		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)			25°C	65	100		65	100		dB
V_{O1}/V_{O2}	Crosstalk attenuation	f = 1 kHz to 20 kHz		25°C		120			120		dB
I_O	Output current	V_{CC} = 15 V, V_{ID} = 1 V, V_O = 0	Source	25°C	−20	−30	−60	−20	−30	−60	mA
				Full range	−10			−10			
		V_{CC} = 15 V, V_{ID} = −1 V, V_O = 15	Sink	25°C	10	20		10	20		
				Full range	5			5			
		V_{ID} = −1 V, V_O = 200 mV		25°C	12	30		12	30		µA
I_{OS}	Short-circuit output current	V_{CC} at 5 V, GND at −5 V, V_O = 0		25°C		±40	±60		±40	±60	mA
I_{CC}	Supply current (two amplifiers)	V_O = 2.5 V, No load		Full range		0.7	1.2		0.7	1.2	mA
		V_{CC} = MAX, V_O = 0.5 V, No load		Full range		1	2		1	2	

*On products compliant to MIL-PRF-38535, this parameter is not production tested.
† All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 26 V for LM2904 and 30 V for others.
‡ Full range is −55°C to 125°C for LM158A, −25°C to 85°C for LM258A, and 0°C to 70°C for LM358A.
§ All typical values are at T_A = 25°C.

electrical characteristics at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		T_A‡	LM358A			UNIT
					MIN	TYP§	MAX	
V_{IO}	Input offset voltage	V_{CC} = 5 V to 30 V, $V_{IC} = V_{ICR(min)}$, V_O = 1.4 V		25°C		2	3	mV
				Full range			5	
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage			Full range		7	20	µV/°C
I_{IO}	Input offset current	V_O = 1.4 V		25°C		2	30	nA
				Full range			75	
$\alpha_{I_{IO}}$	Average temperature coefficient of input offset current			Full range		10	300	pA/°C
I_{IB}	Input bias current	V_O = 1.4 V		25°C		−15	−100	nA
				Full range			−200	
V_{ICR}	Common-mode input voltage range	V_{CC} = 30 V		25°C	0 to V_{CC} − 1.5			V
				Full range	0 to V_{CC} −2			
V_{OH}	High-level output voltage	$R_L \geq 2$ kΩ		25°C	V_{CC} − 1.5			V
		V_{CC} = 30 V	R_L = 2 kΩ	Full range	26			
			$R_L \geq 10$ kΩ	Full range	27	28		
V_{OL}	Low-level output voltage	$R_L \leq 10$ kΩ		Full range		5	20	mV
A_{VD}	Large-signal differential voltage amplification	V_{CC} = 15 V, V_O = 1 V to 11 V, $R_L \geq 2$ kΩ		25°C	25	100		V/mV
				Full range	15			
CMRR	Common-mode rejection ratio			25°C	65	80		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)			25°C	65	100		dB
V_{O1}/V_{O2}	Crosstalk attenuation	f = 1 kHz to 20 kHz		25°C		120		dB
I_O	Output current	V_{CC} = 15 V, V_{ID} = 1 V, V_O = 0	Source	25°C	−20	−30	−60	mA
				Full range	−10			
		V_{CC} = 15 V, V_{ID} = −1 V, V_O = 15 V	Sink	25°C	10	20		
				Full range	5			
		V_{ID} = −1 V, V_O = 200 mV		25°C		30		µA
I_{OS}	Short-circuit output current	V_{CC} at 5 V, GND at −5 V, V_O = 0		25°C		±40	±60	mA
I_{CC}	Supply current (two amplifiers)	V_O = 2.5 V, No load		Full range		0.7	1.2	mA
		V_{CC} = MAX, V_O = 0.5 V, No load		Full range		1	2	

† All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 26 V for LM2904 and 30 V for others.
‡ Full range is −55°C to 125°C for LM158A, −25°C to 85°C for LM258A, and 0°C to 70°C for LM358A.
§ All typical values are at T_A = 25°C.

operating conditions, V_{CC} = ±15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
SR	Slew rate at unity gain	R_L = 1 MΩ, C_L = 30 pF, V_I = ±10 V (see Figure 1)	0.3	V/μs
B_1	Unity-gain bandwidth	R_L = 1 MΩ, C_L = 20 pF (see Figure 1)	0.7	MHz
V_n	Equivalent input noise voltage	R_S = 100 Ω, V_I = 0 V, f = 1 kHz (see Figure 2)	40	nV/√Hz

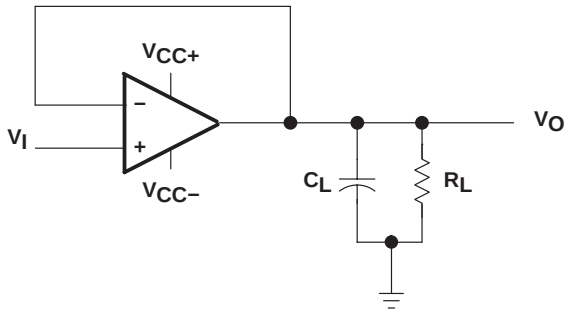


Figure 1. Unity-Gain Amplifier

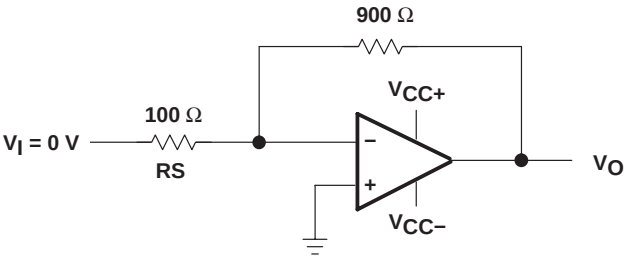


Figure 2. Noise-Test Circuit

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
5962-87710012A	ACTIVE	LCCC	FK	20	1	None	POST-PLATE	Level-NC-NC-NC
5962-8771001PA	ACTIVE	CDIP	JG	8	1	None	A42 SNPB	Level-NC-NC-NC
5962-87710022A	ACTIVE	LCCC	FK	20	1	None	POST-PLATE	Level-NC-NC-NC
5962-8771002PA	ACTIVE	CDIP	JG	8	1	None	A42 SNPB	Level-NC-NC-NC
LM158AFKB	ACTIVE	LCCC	FK	20	1	None	POST-PLATE	Level-NC-NC-NC
LM158AJG	ACTIVE	CDIP	JG	8	1	None	A42 SNPB	Level-NC-NC-NC
LM158AJGB	ACTIVE	CDIP	JG	8	1	None	A42 SNPB	Level-NC-NC-NC
LM158FKB	ACTIVE	LCCC	FK	20	1	None	POST-PLATE	Level-NC-NC-NC
LM158JG	ACTIVE	CDIP	JG	8	1	None	A42 SNPB	Level-NC-NC-NC
LM158JGB	ACTIVE	CDIP	JG	8	1	None	A42 SNPB	Level-NC-NC-NC
LM258AD	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM258ADGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
LM258ADR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM258AP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM258D	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM258DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
LM258DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM258P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM2904AVQDR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
LM2904AVQPWR	ACTIVE	TSSOP	PW	8	2000	None	CU NIPDAU	Level-1-250C-UNLIM
LM2904D	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM2904DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
LM2904DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM2904P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM2904PSR	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM2904PW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM2904PWLE	OBSOLETE	TSSOP	PW	8		None	Call TI	Call TI
LM2904PWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM2904QD	OBSOLETE	SOIC	D	8		None	Call TI	Call TI
LM2904QDR	OBSOLETE	SOIC	D	8		Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM

Orderable Device	Status [1]	Package Type	Package Drawing	Pins	Package Qty	Eco Plan [2]	Lead/Ball Finish	MSL Peak Temp [3]
LM2904QP	OBSOLETE	PDIP	P	8		None	Call TI	Call TI
LM2904VQDR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
LM2904VQPWR	ACTIVE	TSSOP	PW	8	2000	None	CU NIPDAU	Level-1-250C-UNLIM
LM358AD	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM358ADGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
LM358ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM358AP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM358APW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM358APWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM358D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM358DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
LM358DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM358P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM358PSLE	OBSOLETE	SO	PS	8		None	Call TI	Call TI
LM358PSR	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM358PW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM358PWLE	OBSOLETE	TSSOP	PW	8		None	Call TI	Call TI
LM358PWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
None: Not yet available Lead (Pb-Free).
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

[3] MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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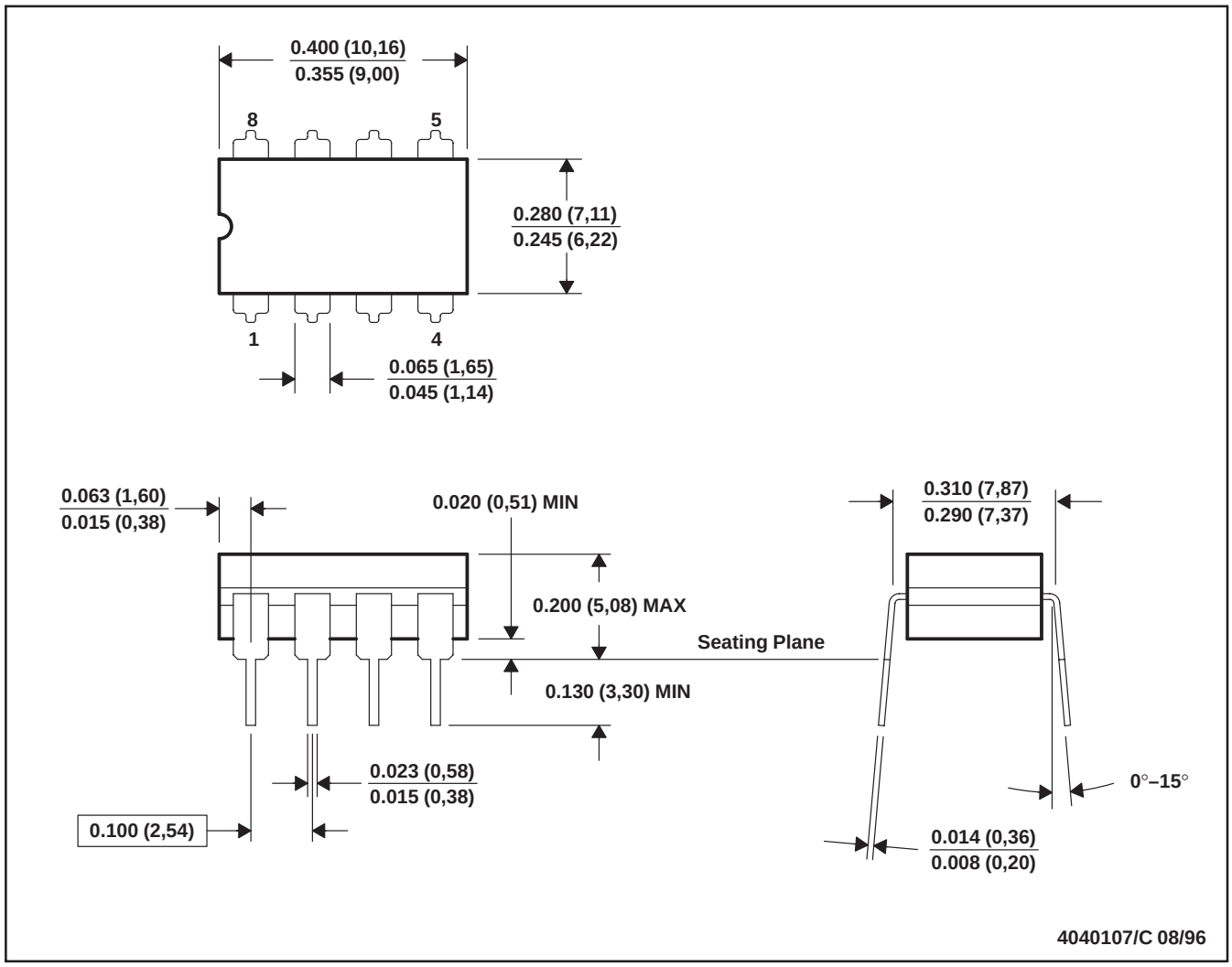
MCER001A – JANUARY 1995 – REVISED JANUARY 1997

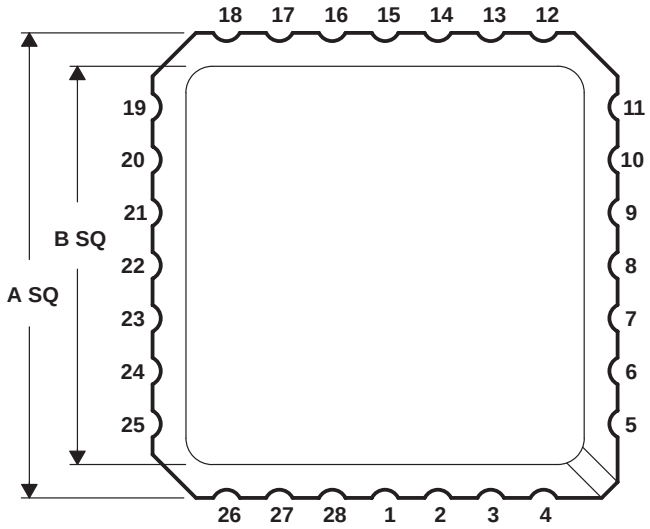
JG (R-GDIP-T8) **CERAMIC DUAL-IN-LINE**



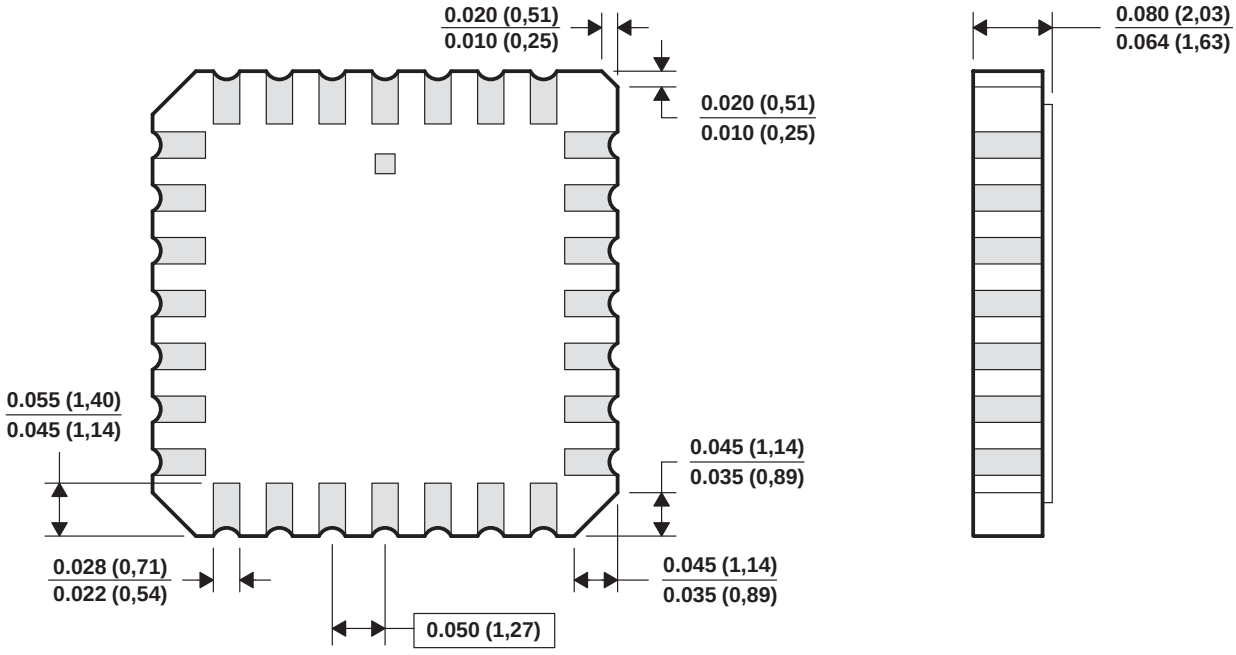
NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification.
E. Falls within MIL STD 1835 GDIP1-T8

FK (S-CQCC-N)** **LEADLESS CERAMIC CHIP CARRIER**

28 TERMINAL SHOWN



NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.739 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)

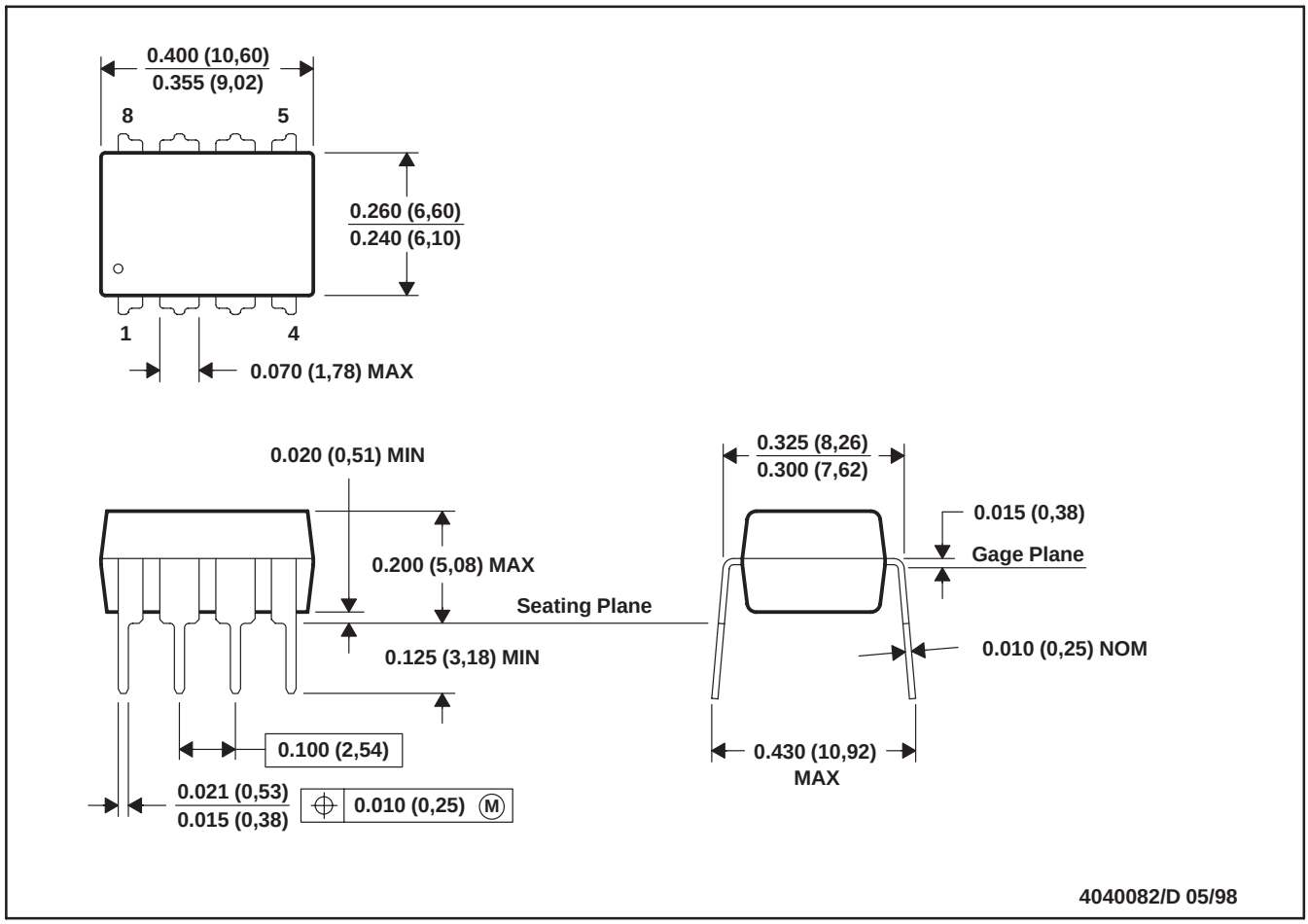


4040140/D 10/96

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a metal lid.
D. The terminals are gold plated.
E. Falls within JEDEC MS-004

MPDI001A – JANUARY 1995 – REVISED JUNE 1999

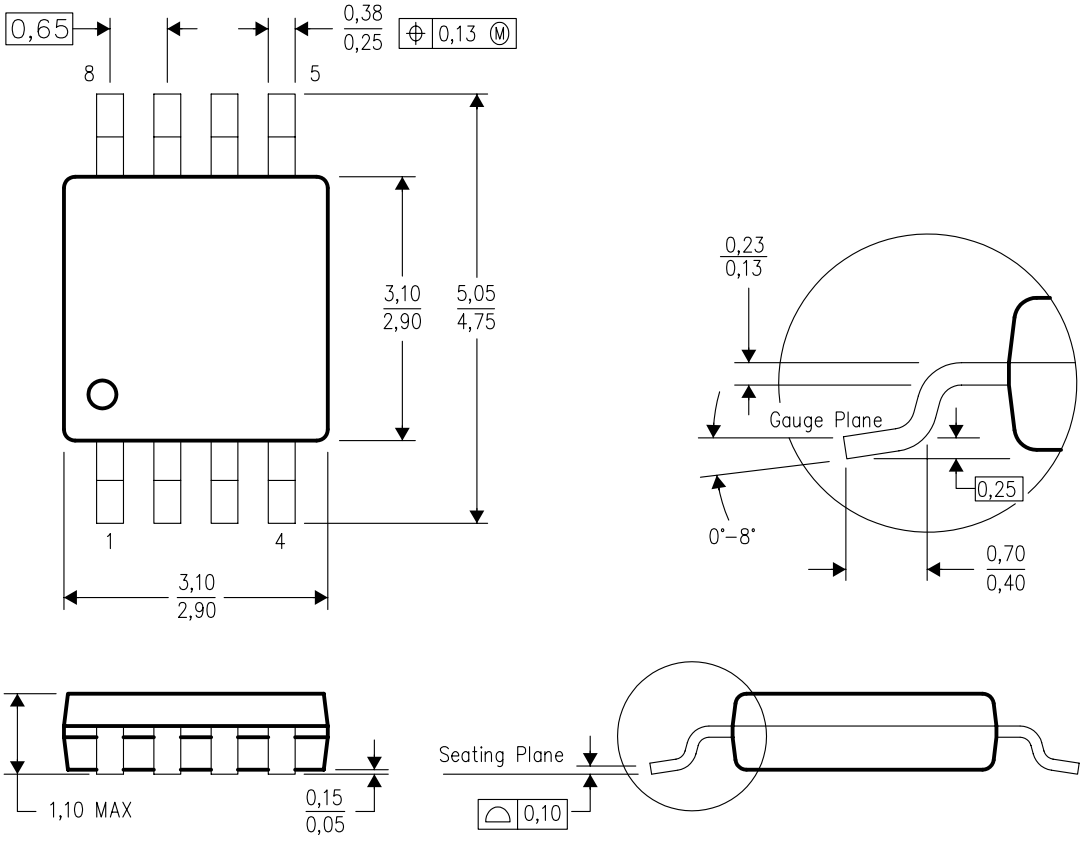
P (R-PDIP-T8) **PLASTIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm

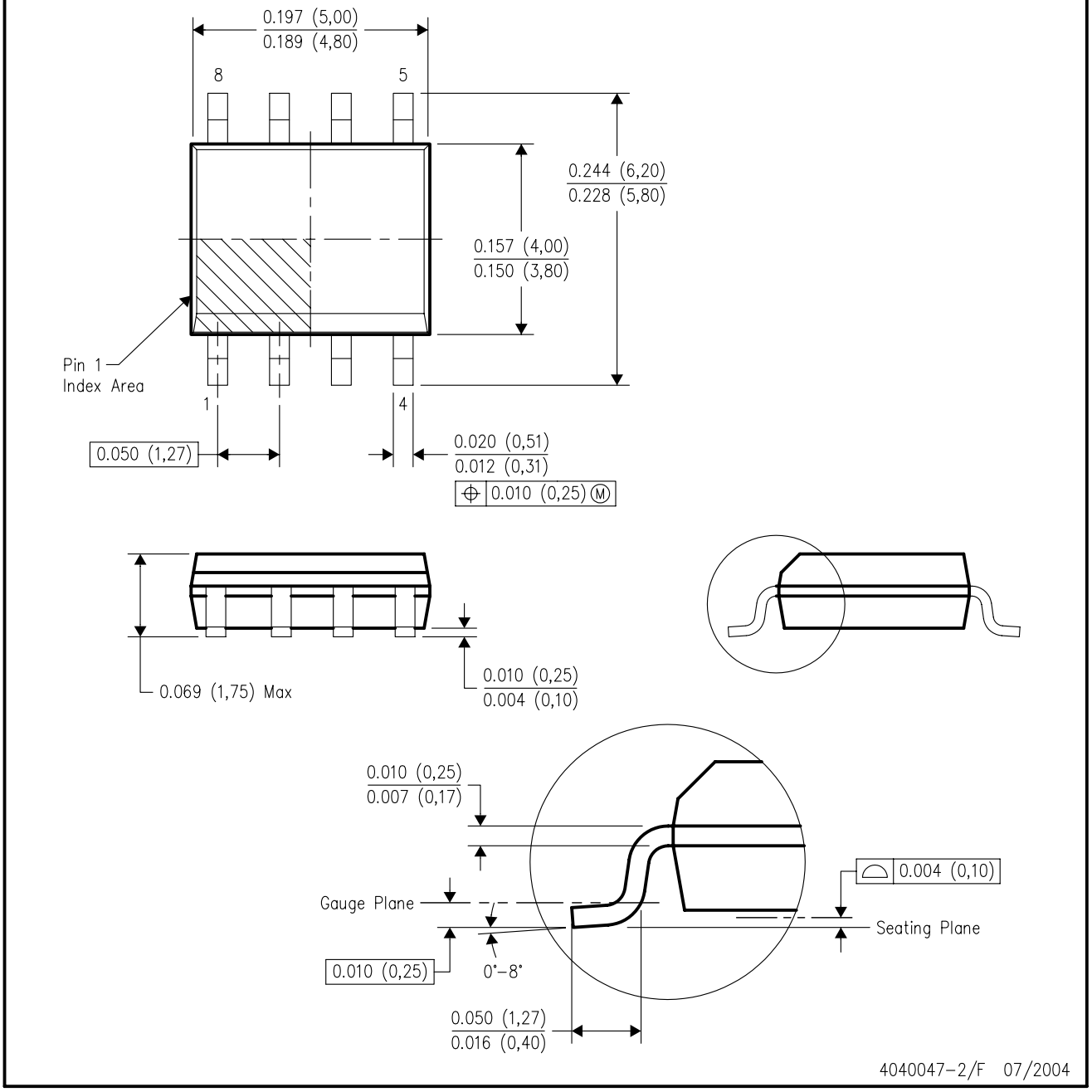
DGK (S–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



4073329/D 12/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. Falls within JEDEC MO–187 variation AA.

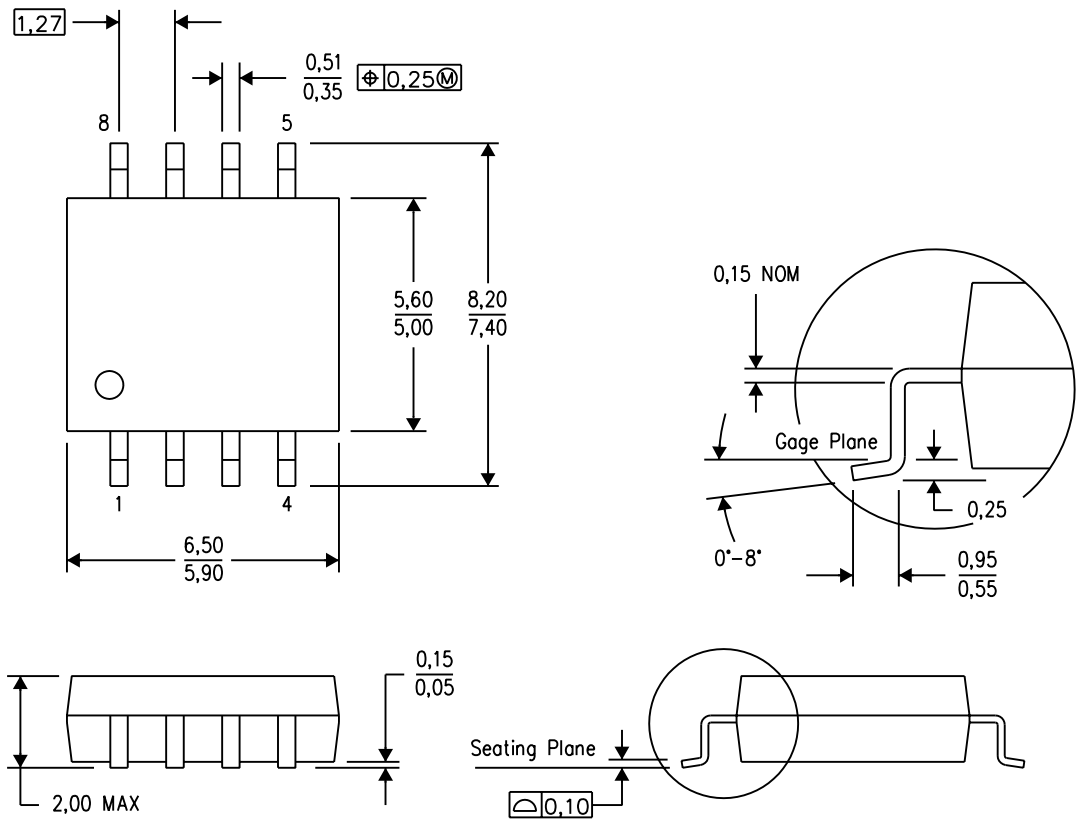
D (R–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS–012 variation AA.

MECHANICAL DATA

PS (R-PDSO-G8) **PLASTIC SMALL-OUTLINE PACKAGE**

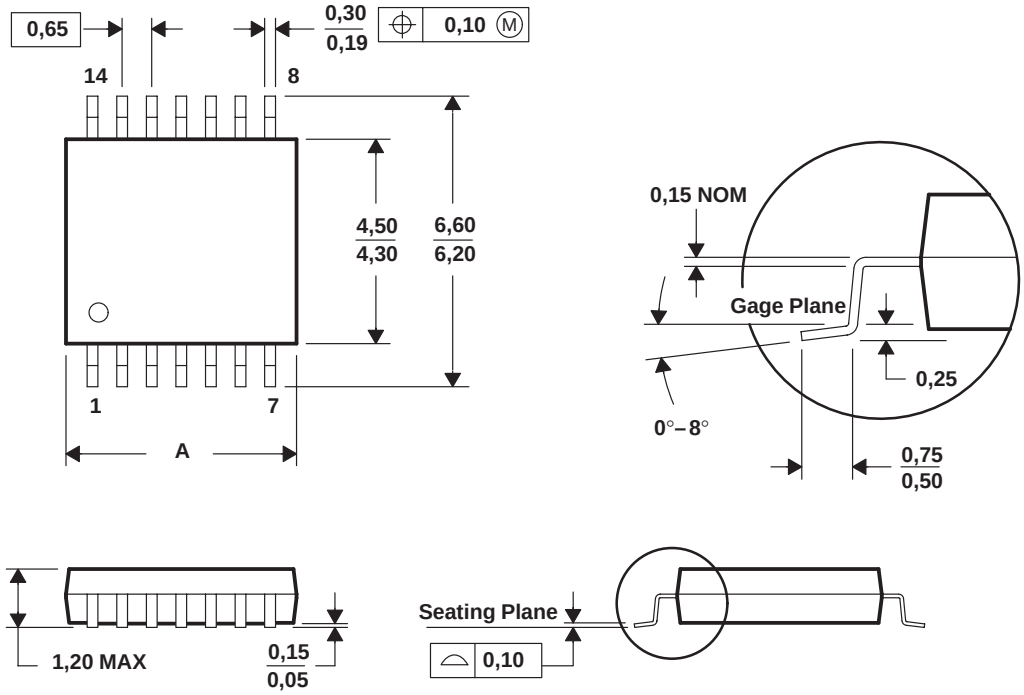


4040063/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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Mailing Address: Texas Instruments
Post Office Box 655303 Dallas, Texas 75265